SIEMENS

TDA 5660 P
Modulator for TV, Video and Sound Signals

The monolithically integrated circuit TDA 5660 P is especially suitable as modulator for the 48 to 860 MHz frequency range and is applied e.g. in video recorders, cable converters, TV converter installations, demodulators, video generators, video security systems, amateur TV applications, as well as personal computers.

- Synchronizing level-clamping circuit
- Peak white value gain control
- Continuous adjustment of modulation index for positive and negative modulation
- Dynamic residual carrier setting
- FM sound modulator
- AM sound modulator
- Picture carrier to sound carrier adjustment
- Symmetrical mixer output
- Symmetrical oscillator with own RF ground
- Low radiation
- Superior frequency stability of main oscillator
- Superior frequency stability of sound oscillator
- Internal reference voltage

Circuit description

Via pin 1, the sound signal is capacitively coupled to the AF input for the FM modulation of the oscillator. An external circuitry sets the preemphasis. This signal is forwarded to a mixer which is influenced by the AM modulation input of pin 16. The picture to sound carrier ratio can be changed by connecting an external voltage to pin 16, which deviates from the internal reference voltage. In case, the sound carrier should not be FM but AM modulated, pin 1 should be connected to pin 2, while the AF signal is capacitively coupled to pin 16. Through an additional external dc voltage at pin 16, the set AM modulation index can be changed by overriding the internally adjusted control voltage for a fixed AM modulation index. At the output of the above described mixer the FM and/or AM modulated sound signal is added to the video signal and mixed with the oscillator signal in the RF mixer. A parallel resonant circuit is connected to the sound carrier oscillator at pin 17, 18. The unloaded Q of the resonant circuit must be $Q = 25$ and the parallel resistor $R_T = 6.8\ k\Omega$ to ensure a picture to sound carrier ratio of 12.5 dB. At the same time, the capacitative and/or inductive reactance for the resonance frequency should have a value of $X_C \approx X_L \approx 800\ \Omega$.

The video signal with the negative synchronous level is capacitively connected to pin 10. The internal clamping circuit is referenced to the synchronizing level. Should the video signal change by 6 dB, this change will be compensated by the resonant circuit which is set to the peak white value. At pin 11, the current pulses of the peak white detector are filtered through the capacitor which also determines the control time constant. When pin 12 is connected to ground, the RF carrier switches from negative to positive video modulation.

With the variable resistor of $R = \infty \dots 0\ \Omega$ at pin 12, the modulation depth, beginning with $R = \infty$ and a negative modulation of $m_{D/N} = 80\%$, can be increased to $m_{D/N} = 100\%$ and continued with a positive modulation of $m_{D/P} = 100\%$ down to $m_{D/P} = 88\%$ with $R = 0\ \Omega$. The internal reference voltage has to be capacitively blocked at pin 2.

The amplifier of the RF oscillator is available at pins 3-7. The oscillator operates as a symmetrical ECO circuit. The capacitive reactance for the resonance frequency should be $X_C \approx 70\ \Omega$ between pins 3, 4 and 6, 7 and $X_C \approx 26\ \Omega$ between pins 4, 6. In order to set the required residual carrier suppression, pin 9 is used to compensate for any dynamic asymmetry of the RF mixer during high frequencies of > 300 MHz. The oscillator chip ground, pin 5, should be connected to ground at the oscillator resonant circuit shielding. Via pin 3 and 7 an external oscillator signal can be injected inductively or capacitively. The peripheral layout of the pc board should be provided with a minimum shielding attenuation of approx. 80 dB between the oscillator pins 3-7 and the modulator outputs 13-15.

For optimum residual carrier suppression, the symmetric mixer outputs at pins 13, 15 should be connected to a matched balanced-to-unbalanced broadband transformer with excellent phase precision at 0 and 180 degrees, e.g. a Guanella transformer. The transmission loss should be less than 3 dB. In addition, an LC low pass filter combination is required at the output. The cut-off frequency of the low pass filter combination must exceed the maximum operating frequency.

If the application circuit according to figure 1, 2 is used, a multiplication factor V/RF (application) = V/RF (data sheet) 3.9 must be used to convert a 300 Ω symmetrical impedance to an asymmetrical impedance of 75 Ω for the stated RF output voltage V_q of the type specification in order to ensure a transmission attenuation of 0 dB for the balanced-to-unbalanced mixer.

Maximum ratings

		min	max		Remarks
Supply voltage	V_S	−0.3	14.5	V	
Current from pin 2	$-I_2$	0	2	mA	$V_2 = 7$ to 8 V $V_S = 9.5$ to 13.5 V
Voltage at pin 1	V_1	$V_2 - 2$	$V_2 + 2$	V	$V_S = 9.5$ to 13.5 V
Voltage at pin 9	V_9	−4	1	V	
Voltage at pin 10	$V_{10\,pp}$		1.5	V	only via C (max. 1 µF)
Capacitance at pin 2	C_2	0	100	nF	
Capacitance at pin 11	C_{11}	0	15	µF	
Voltage at pin 12	V_{12}	−0.3	1.4	V	
Voltage at pin 13	V_{13}	V_2	V_S	V	
Voltage at pin 15	V_{15}	V_2	V_S	V	
Voltage at pin 16	V_{16}	$V_2 - 1.5$	$V_2 + 1.5$	V	$V_S = 9.5$ to 13.5 V
Only the external circuitry shown in application circuits 1 and 2 may be connected to pins 3, 4, 6, 7, 17 and 18					
Junction temperature	T_j		150	°C	
Storage temperature	T_{stg}	−40	125	°C	
Thermal resistance (system-air)	$R_{th\,SA}$		80	K/W	

Operating range

Supply voltage	V_S	9.5	13.5	V	
Video input frequency	f_{VIDEO}	0	5	MHz	
Sound input frequency	f_{AF}	0	20	kHz	
Output frequency	f_q	48	860	MHz	depending on the oscillator circuitry at pins 3-7
Ambient temperature	T_A	0	70	°C	
Sound oscillator	f_{OSC}	4	7	MHz	
Voltage at pin 13, 15	$V_{13,15}$	V_2	V_S	V	

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Characteristics
$V_S = 11$ V; $T_A = 25\,°C$

		Test conditions	Figure	min	typ	max	
Current consumption	I_8	$I_2 = 0$ mA	1; 2	22	30	40	mA
Reference voltage	V_2	$0 \le I_2 \le 1$ mA	1; 2	7	7.5	8	V
Oscillator frequency range	f_{OSC}	External circuitry adjusted to frequency		48		860	MHz
Turn-on start-up drift	Δf_{OSC}	TC value of capacitor in osc. circuit is 0; drift is referenced only to self-heating of the component $t = 0.5$-10 s; T_A = const.					
		Ch 30	1; 2	0	–50	–500	kHz
		Ch 40	1; 2	0	–200	–500	kHz
Frequency drift as function of V_S	$-\Delta f_{OSC}$	$V_S = 9.5$-13.5 V	1; 2	0			
		T_A = const. Ch 40		–150		150	kHz
Video input current at pin 10	$-I_{10}$	$C_{10} \le 1$ µF	5	0		10	µA
Video input voltage at pin 10	$V_{10\,pp}$	at coupling capac. $C \le 1$ µF $I_{leak} \le \pm 0.3$ µA	21; 22	0.7		1.4	V
Modulation depth	$m_{D/N}$	neg. mod.	1; 16	75	80	85	%
$V_{VIDEO\,pp} = 1$ V; $f_{VIDEO} = 200$ kHz sine signal	$m_{D/P}$	pos. mod.	2; 16	83	88	93	%
Output impedance	Z_{13}; Z_{15}	static	24	10			kΩ
RF output voltage Modulation signal in neg. modulation pin 12 open	$V_{q\,rms}$	Ch 40	1b	2.5	3.5	5.5	mV
Output capacitance	C_{13}–C_{15}		25	0.5	1	2.0	pF
S parameter at pins 3, 4 and 6, 7			26				
RF output phase	$\alpha_{13,15}$			140	180	220	degrees
RF output voltage change; adjustment range	ΔV_q	$f = 543.25$-623.25 $\Delta f = 80$ MHz Ch 30-Ch 40	1	0		1.5	dB
RF output voltage change	ΔV_q	$f = 100$-300 MHz	6	0		1.5	dB
RF output voltage change	ΔV_q	$f = 48$-100 MHz	6	0		1.5	dB
Oscillator interference FM caused by AM modulation and coupling of the modulator output with the oscillator resonant circuit; $V_{VIDEO\,pp} = 1$ V; $f_{VIDEO} = 10$ kHz; sine signal	Ch 30		1; 9	0	5	15	kHz
	Ch 40		1; 9	0	7	21	kHz

Characteristics

$V_S = 11$ V; $T_A = 25$ °C

		Test conditions	Figure	min	typ	max	
Intermodulation ratio	a_{MR}	f_P +1.07 MHz	1; 7; 15	54	75		dB
Harmonic wave ratio	a_H	f_P +8.8 MHz without video signal 19, 20, 21 unmodulated video and sound carrier, measured with the spectrum analyzer as difference between video carrier signal level and sideband signal level without video and sound modulation.	1; 7; 15	35			dB
Harmonic wave ratio	a_H	$f_P + 2f_S$	1; 7	35	48		dB
Harmonic wave ratio	a_H	$f_P + 3f_S$ V_q with spectrum analyzer; loaded Q factor Q_L of the sound oscillator resonant circuit adjusted by R_S to provide the required picture to sound carrier ratio of 12.5 dB; R_S = 6.8 kΩ; Q_U = 25 of the sound oscillator circuit.	1; 7	42	48		dB
Sound carrier ratio	$a_{P/S}$		1; 7; 17	10	12.5	15	dB
Color picture to sound carrier ratio	a_P	f_P +4.4 MHz (dependent on video signal)	1		17		dB
All remaining harmonic waves	a	Multiple of fundamental wave of picture carrier, without video signal, measured with spectrum analyzer; $f_{P/S}$ = 523.25-623.25 MHz	1	15			dB
Amplitude response of the video signal	a_V	$V_{VIDEO\ pp}$ = 1 V with additional modulation f = 15 kHz-5 MHz sine signal between black and white	1; 13	0		1.5	dB
Residual carrier suppression	a_R	With adjustment at pin 9 Ch 30…Ch 40	1; 12	32			
Static mixer balance characteristic	$\Delta V_{13/15}$	V_9 adjusted to $\Delta V_{13/15}$ minimum	21; 23	–100	0	+100	mV
Dynamic mixer balance characteristics	$V_{13\ rms}$	V_9 adjusted to $V_{13\ rms}$ minimum	21; 23		0	10	mV
Stability of set modulation depth	Δm_D	Video input voltage changes with sine signals f = 0.2 MHz; $\Delta V_{VIDEO\ pp}$ = 1 V ± 3 dB; Ch 30…Ch 40; V_S = 12 V; T_A = const.			1	±2.5	%
Stability of set modulation depth	Δm_D	f = 48…100 MHz	6		1	±2.5	%
Stability of set modulation depth	Δm_D	f = 100…300 MHz	6		2	±4	%
Stability of set modulation depth	Δm_D	T_A = 0-60 °C; V_S = 12 V	1		1	±2.5	%

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Characteristics

$V_S = 11$ V; $T_A = 25$ °C

		Test conditions	Figure	min	typ	max	
Stability of set modulation depth	Δm_D	$V_S = 9.5$-13; 5 V; T_A = const.	1		1	±2.5	%
Interference product ratio sound in video; sound carrier FM mod.	$a_{S/P}$	Ch 30…Ch 40	1; 11	48	60		dB
Signal-to-noise ratio in video; sound carrier unmodulated	$a_{N/P}$	Ch 30…Ch 40	1; 11	48	74		dB
Interference product ratio sound in video sound carrier AM mod.	$a_{S/P}$	Ch 30…Ch 40	1; 11	20	33		dB
Umweighted FM noise level ratio video in sound; FuBK test picture as video signal	$a_{P/S}$	Ch 39	1a; 8	48	54		dB
Unweighted FM noise level ratio video in sound	$a_{P/S}$	Ch 39; test picture VU G-Y; U/V	2; 8	48	56		dB
		Ch 39; color bar	2; 8	46	52		dB
		Ch 39; uniform red level	2; 8	48	58		dB
		Ch 39; uniform white level	2; 8	45	51		dB
		Ch 39; test pattern	2; 8	48	55		dB
		Ch 39; white bar	2; 8	46	52		dB
		Ch 39; bar	2; 8	45	50.8		dB
		Ch 39; 20T/2T	2; 8	43	49		dB
		Ch 39; 30% white level	2; 8	48	58		dB
		Ch 39; 250 kHz	2; 8	46	52		dB
		Ch 39; multiburst	2; 8	46	53		dB
		Ch 39; ramp	2; 8	44	50		dB
Signal-to-noise ratio of sound oscillator	$a_{S/N}$		1a; 8	48	54		dB
Differential gain	G_{dif}	measured with measurement demodulator, video test signals and vector scope	1			10	%
Differential phase	φ_{dif}		1			15	%
Period required for peak white detector to reach steady state for full modulation depth with 1 white pulse per half frame with control in steady state	t	C at pin 11 = 10 µF; $I_{leak} \leq 2$ µA	1		6	50	µs

Characteristics
$V_S = 11$ V; $T_A = 25$ °C

		Test conditions	Figure	min	typ	max	
Setting time for video signal change from 0 V_{pp} to 1.4 V_{pp}	t	Video blanking signal content is uniform white level	1		120	500	µs
Setting time for video blanking signal from 100% white level to 42% grey level with subsequent rise in grey level to 71% of video blanking signal (due to decontrol process)	t		1		2.25	5	s
Sound oscillator frequency range	$f_{S/OSC}$	Unloaded Q factor of resonant circuit $Q_U = 25$; resonance frequency 5.66 MHz	1	4		7	MHz
Turn-on start-up drift	$\Delta f_{S/OSC}$	Capacitor TC value in sound oscillator circuit is 0, drift is based only on component heating. T_A = const.; $f_{S/OSC} = 5.5$ MHz	1		5	15	kHz
Sound oscillator frequency operating voltage	$\Delta f_{S/OSC}$	$V_S = 9.5\text{-}13.5$ V; $f_{S/OSC} = 5.5$ MHz; T_A = const.; $Q_U = 25$	1		5	15	kHz
FM mod. harmonic distortion	THD_{FM}	$V_{1\,rms} = 150$ mV	19; 19a		0.6	1.5	%
Audio preamplifier input impedance (dyn.); FM operation	Z_1		1	200			kΩ
FM sound modulator, static modulation characteristic	$\Delta f_{S/OSC}$	$\Delta V_{1/2} = V_1 - V_2 = \pm 1$ V; $f_{S/OSC} = 5.5$ MHz; $Q_U = 25$	1; 14	±210	±270	±330	kHz
FM sound modulation characteristic (dynamic)	$\Delta f_M / \Delta V_1$		1a; 10a	0.3	0.38	0.46	kHz/mV
AM sound modulation factor	m	$V_{AF} = 0.3$ V	2; 3; 4a, b	30	40	50	%
AM sound modulation harmonic distortion	THD_{AM}	$m = 86\%$; $V_{AF} = 0.64$ V; $f_{AF} = 1$ kHz			0.7	3	%
AM audio preamplifier input impedance	Z_{16}		2	25	50	75	kΩ
AM sound modulator input voltage	V_{AF}	$m = 90\%$; $f_{AF} = 1$ kHz	2	0.5	0.67	0.84	V

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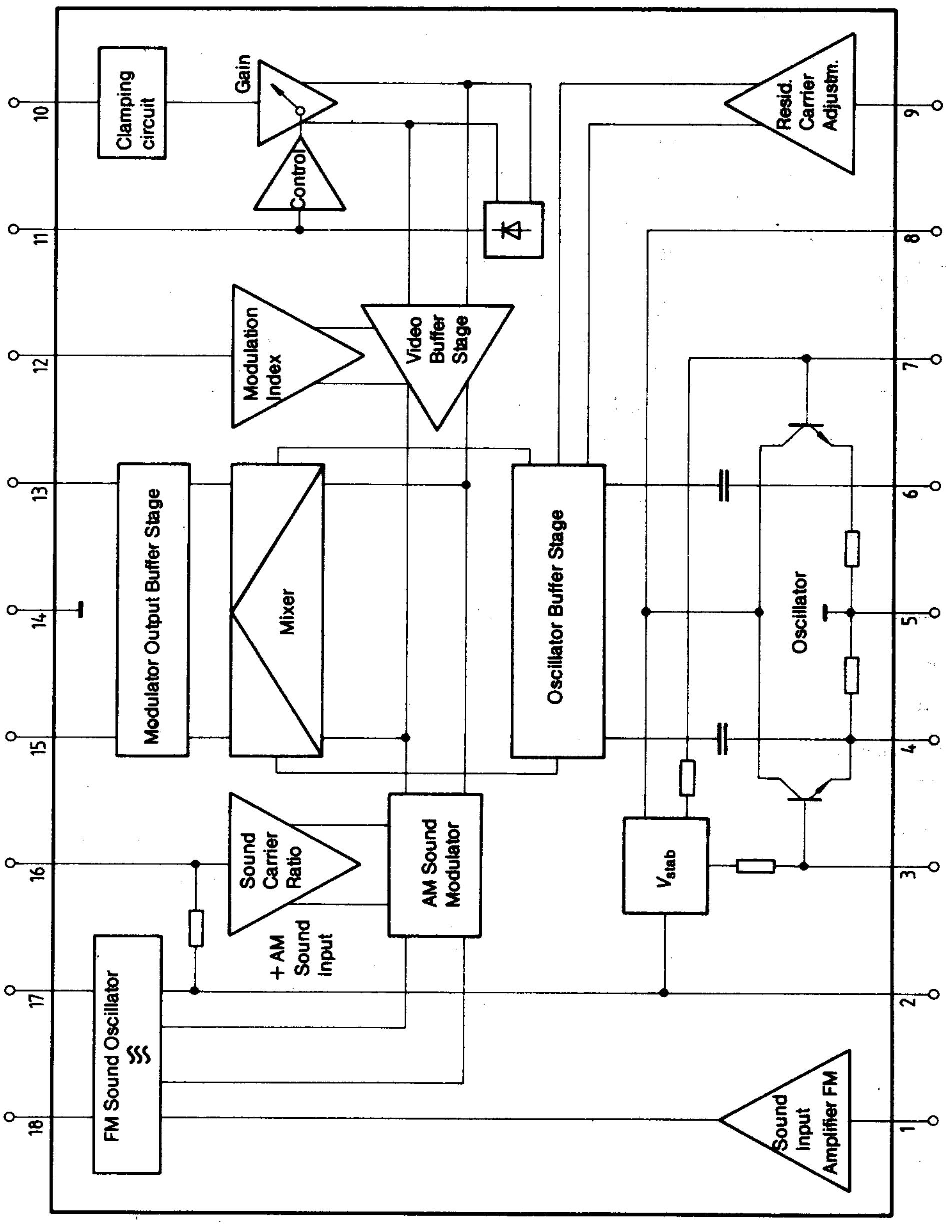
Pin description

Pin	Function
1	AF input for FM modulation
2	Internal reference voltage
3	Symmetrical oscillator input
4	Symmetrical oscillator output
5	Oscillator ground
6	Symmetrical oscillator output
7	Symmetrical oscillator input
8	Supply voltage
9	Dynamic residual carrier adjustment
10	Video input with clamping
11	Connection for smoothing capacitor for video control loop
12	Switch for positive and negative modulation as well as residual carrier control
13	Symmetrical RF output
14	Remaining ground of component
15	Symmetrical RF output
16	Picture to sound carrier ratio (adjustment and AM sound input)
17	Sound oscillator symmetrical input for tank circuit
18	Sound oscillator symmetrical input for tank circuit

Block diagram



Test and measurement circuit 1 for FM sound carrier and negative video modulation

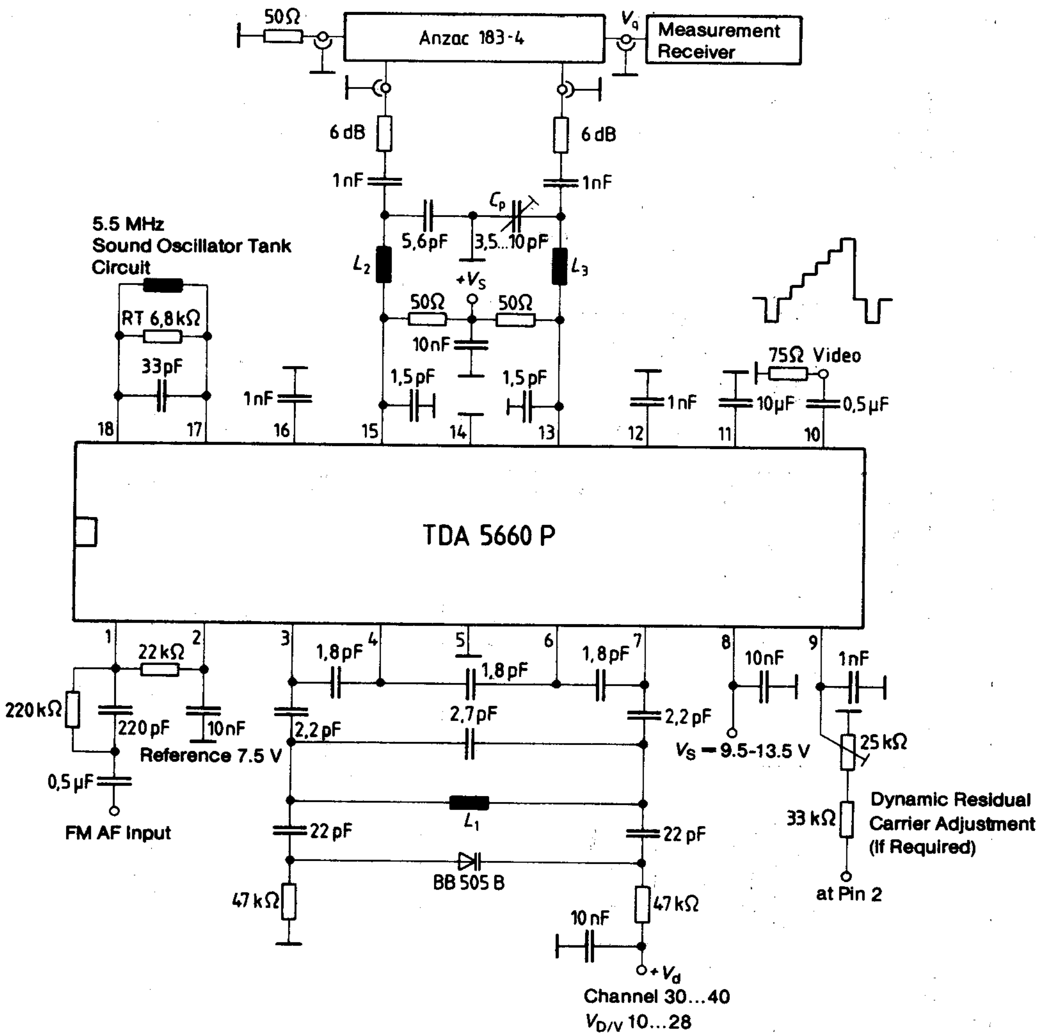


Figure 1

Test and measurement circuit 1 for FM sound carrier and negative video modulation

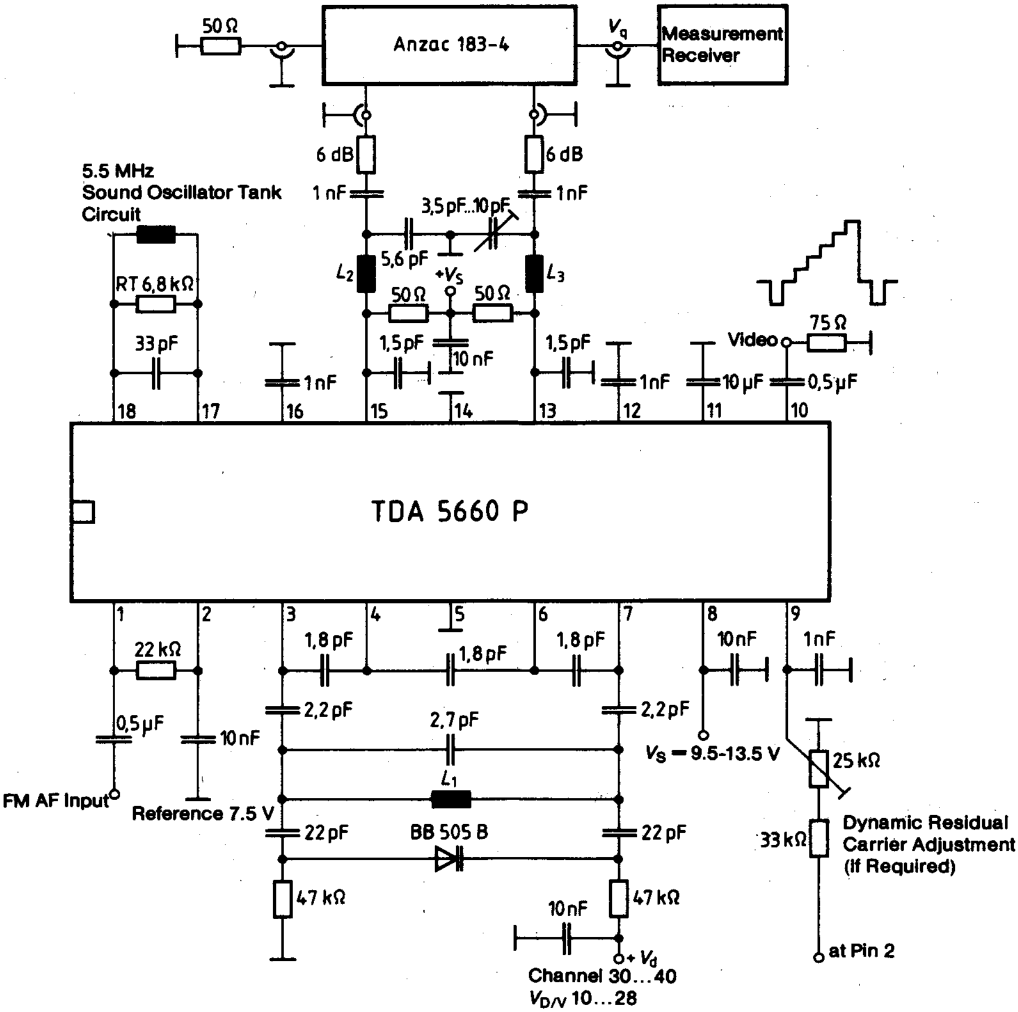


Figure 1a

Test and measurement circuit 1 for FM sound carrier and negative video modulation

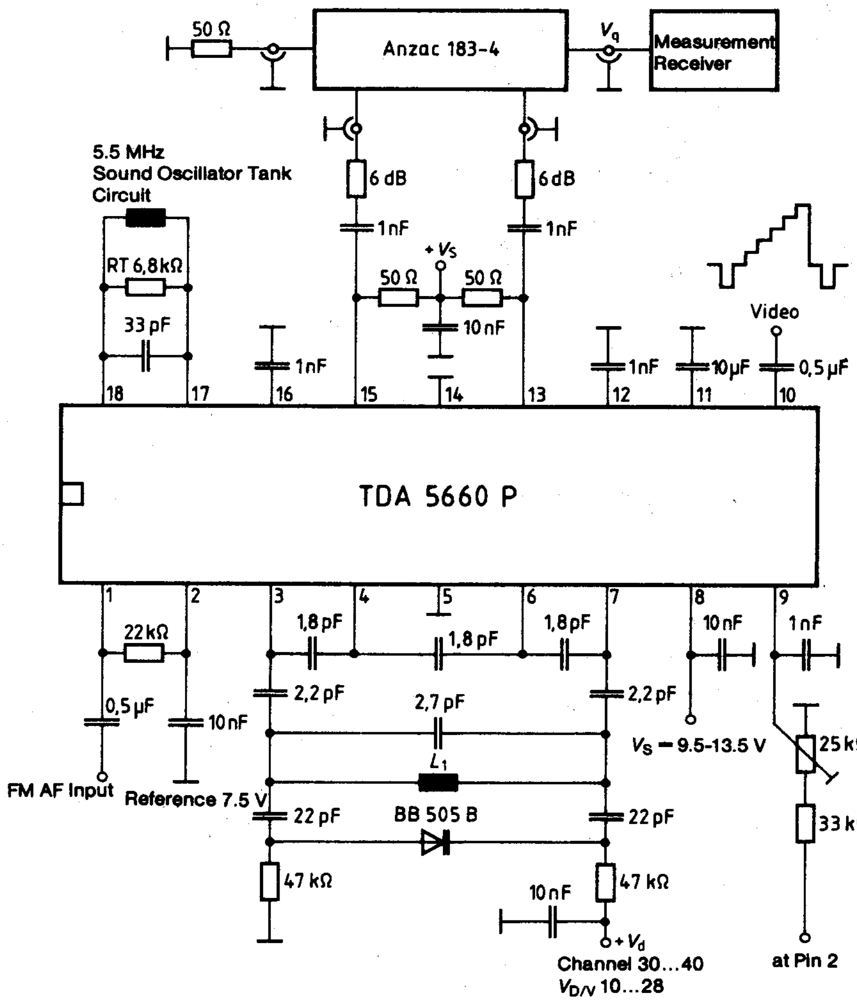


Figure 1 b

Test and measurement circuit 2 for FM sound carrier and negative video modulation

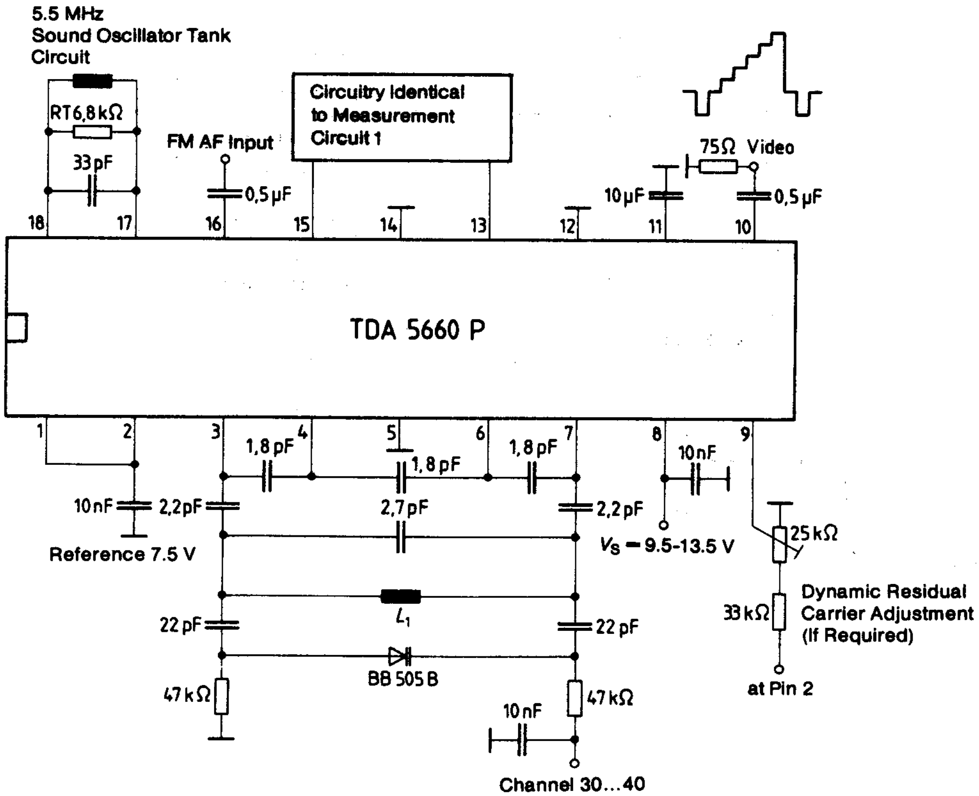


Figure 2

AM sound modulation measurement

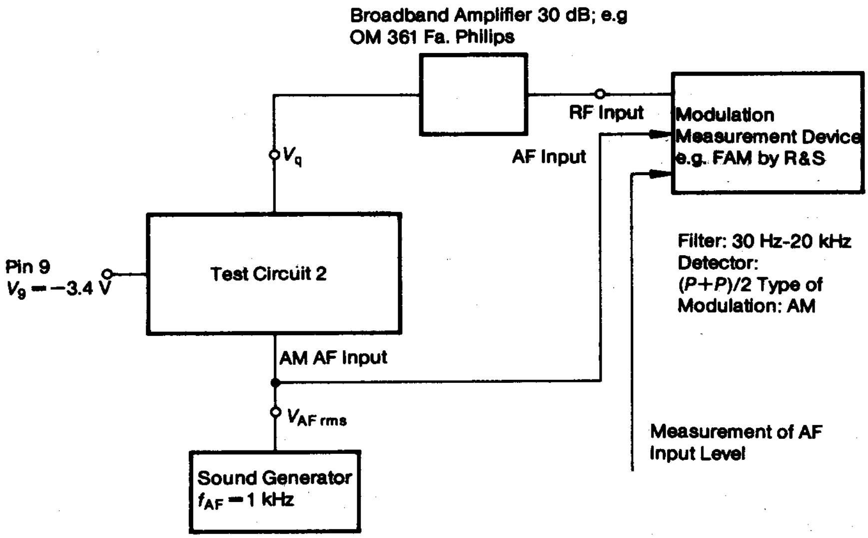


Figure 3

AM sound carrier modulation index versus AF input voltage at pin 16

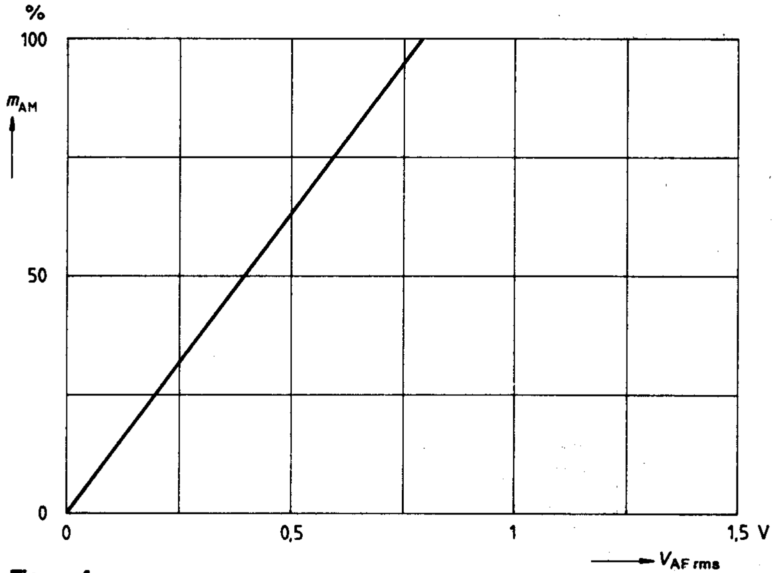


Figure 4 a

AM sound carrier modulation index versus dc voltage offset at pin 16
$V_{AF\,rms} = 0.6$ V; $\Delta V_{16/2}$ (V) = $V_2 - V_{16}$

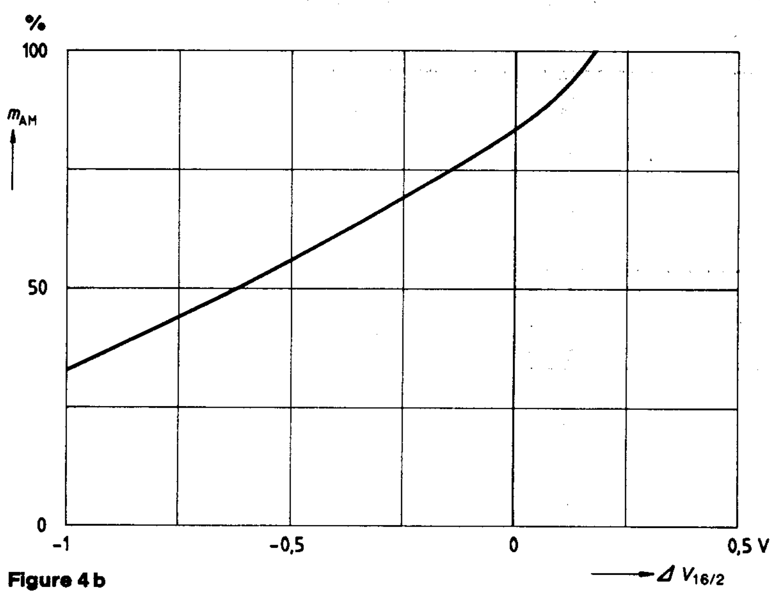


Figure 4 b

Measurement circuits

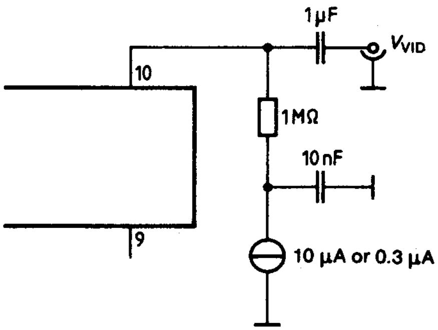


Figure 5

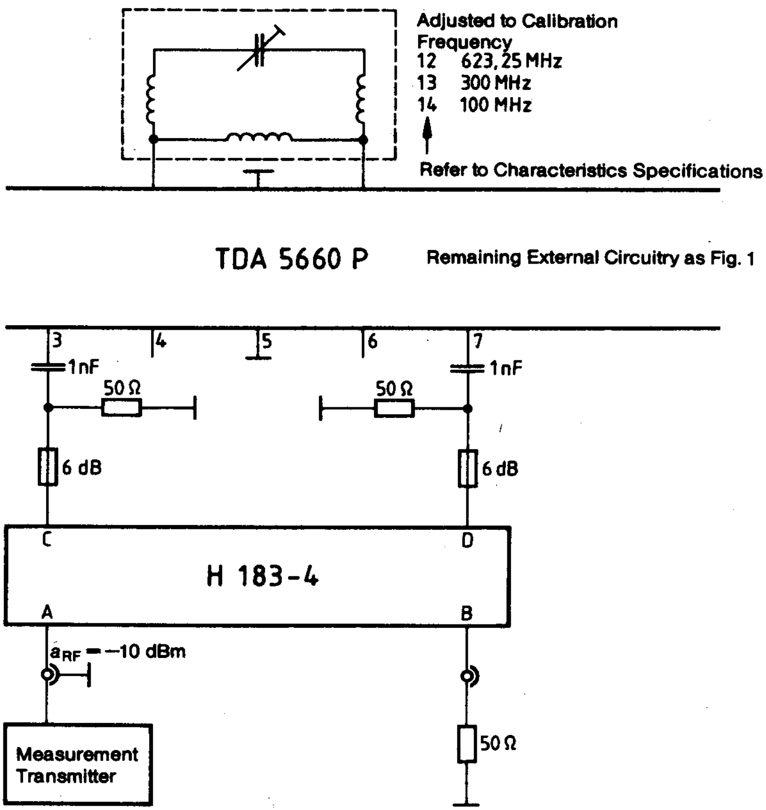


Figure 6

Frequency spectrum above the video carrier, measured at clamp V_q with a spectrum analyzer

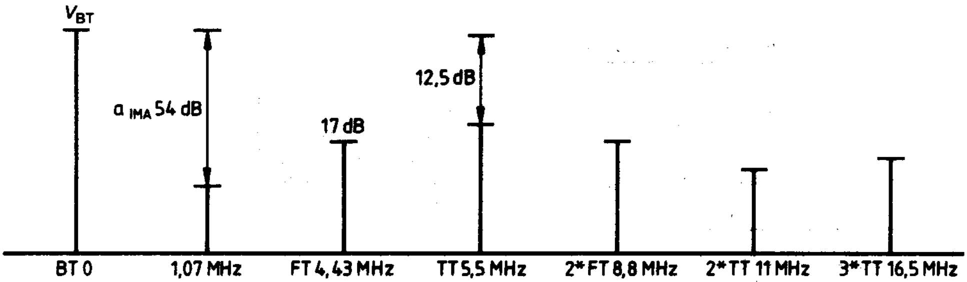


Figure 7

BT – Video Carrier
FT – Frequency Carrier
TT – Sound Carrier

Description of the measurement configuration to measure the noise voltage, video in sound

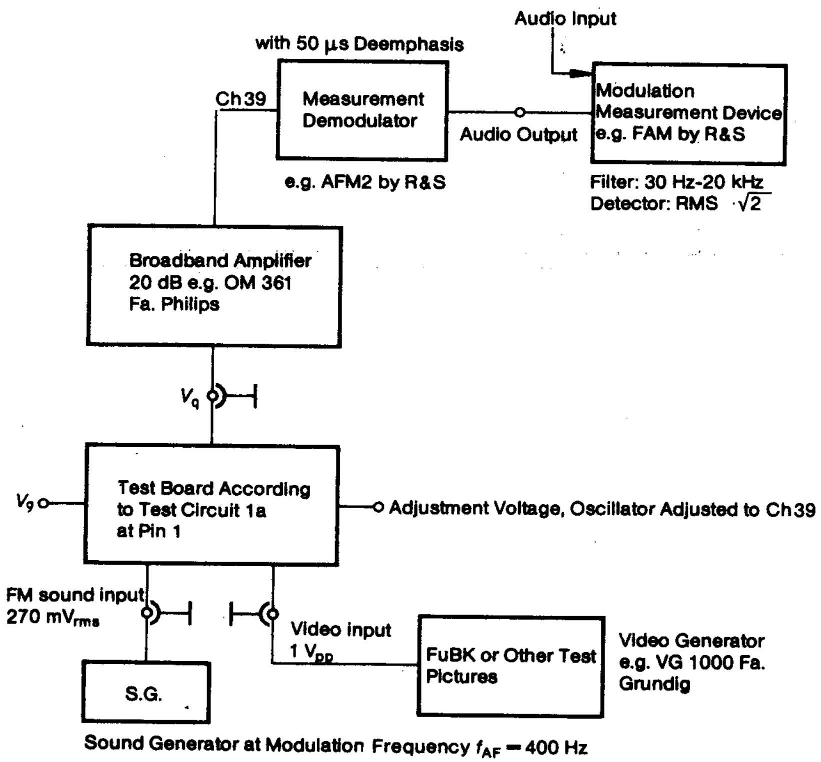


Figure 8

Calibration: A signal of $V_{AF\ rms}$ = 270 mV and f = 0.4 kHz, corresponding to a nominal deviation of 30 kHz, is connected to the sound input, and the demodulated AF reference level at the audio measurement device is defined as 0 dB. No video signal is pending.

Measurement:
1) The AF signal is switched off and the FuBK video signal is connected to the video input with $V_{VIDEO\ pp}$ = 1 V. The audio level in relation to the reference calibration level is measured as ratio $a_{p/s} = 20 \log (V_{FUBK})/(V_{nominal})$.
2) AF and video signal are switched off. The noise ratio in relation to the AF reference calibration level is measured as signal-to-noise ratio $a_{S/N}$.

Description of the measurement configuration to measure the oscillator interference FM

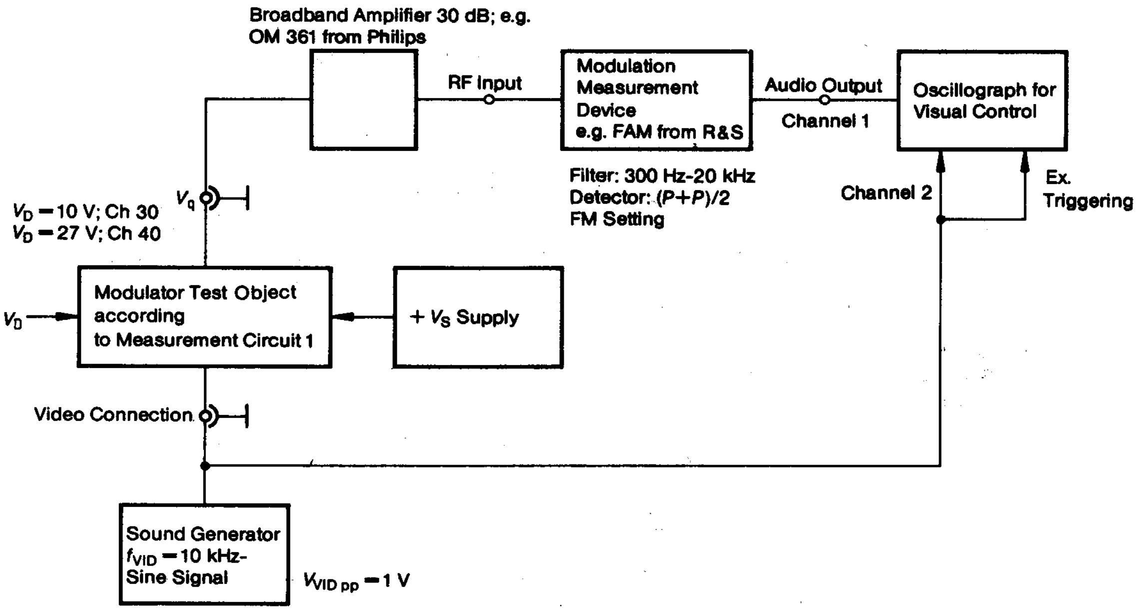


Figure 9

Description of the measurement configuration to measure the total harmonic distortion during FM operation of the sound carrier

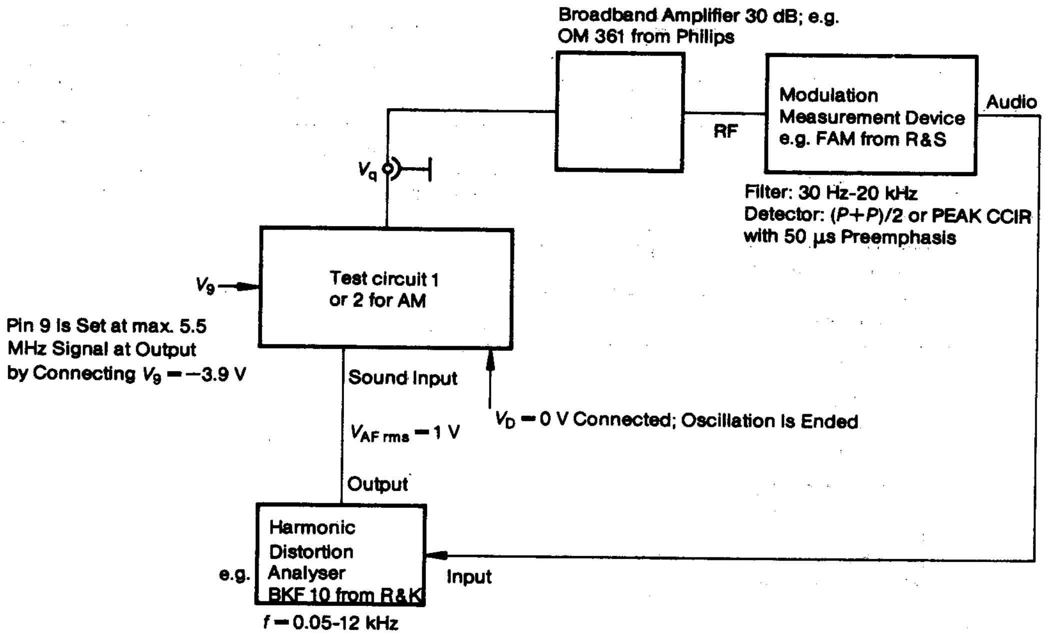


Figure 10

Description of the measurement configuration to measure the total harmonic distortion during FM operation of the sound carrier

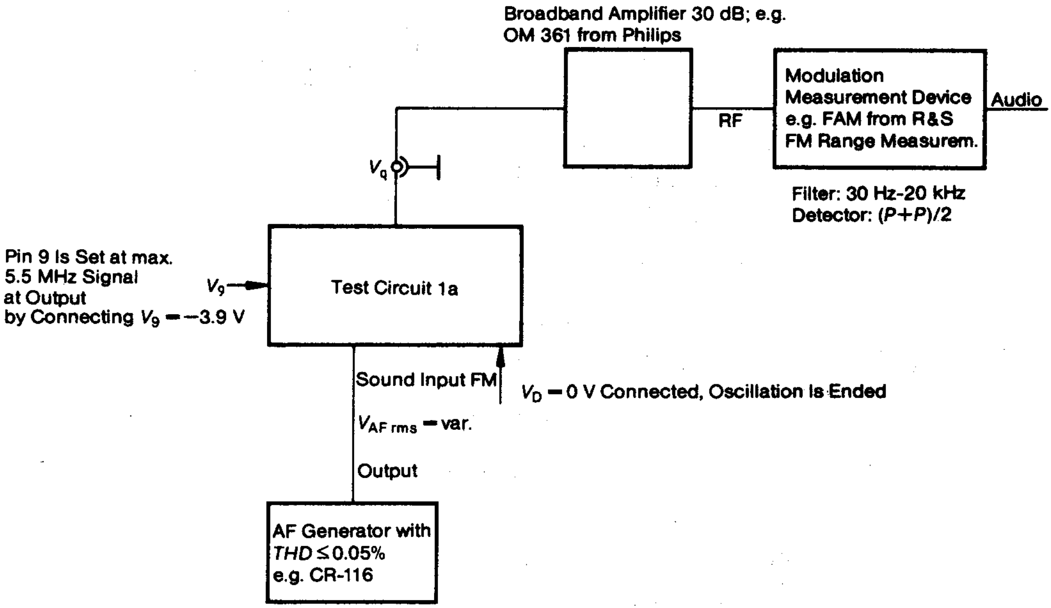


Figure 10 a

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Description of the measurement configuration to measure the sound and/or noise in video during FM and/or AM sound carrier modulation

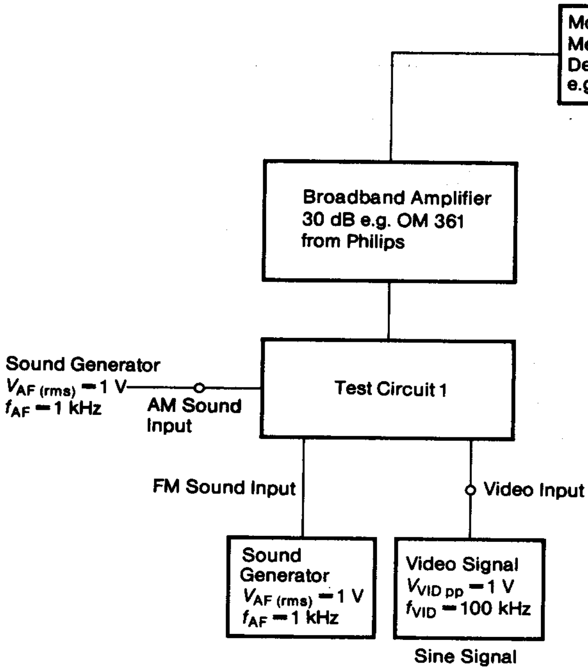


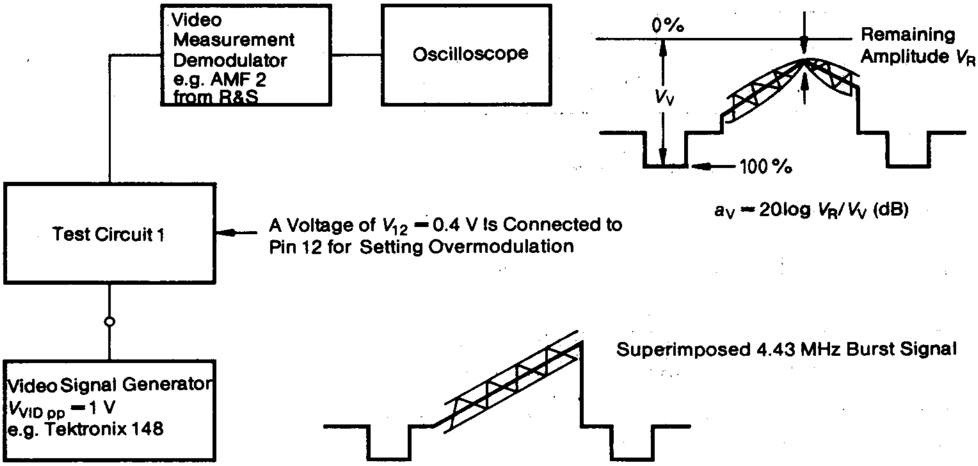
Figure 11

Calibration: AF signals are switched off; video signal is pending at the video input; device to measure modulation set at AM is adjusted to video carrier; filter: 300 Hz…200 kHz; detector $(P+P)/2$; resulting modulation index is defined as $m_V = 0$ dB.

Measurement:

1) Measurement of interference product ratio sound in video during FM modulation of the sound carrier: AF signal is connected to FM sound input; video signal is switched off; device to measure modulation is set to AM; filter: 300 Hz…3 kHz; detector: $(P+P)/2$; a ratio of $a_{S/P} = 20 \log m_{V/S}/\text{mV}$) is derived from the resulting modulation index $m_{V/S}$.
2) Measurement of interference product ratio sound in video during AM modulation of sound carrier: AF signal is connected to AM sound input; otherwise identical with measurement 1.
3) Measurement of signal-to-noise ratio in video without AM/FM modulation of sound carrier: AF signals are switched off; video signal is switched off; control voltage at pin 11 is clamped to value present during connected video signal; modulation device is set to AM; filter: 300 Hz…3 kHz; detector: RMS $\sqrt{2}$; readout in dB to reference level of calibration is $a_{S/P}$.

Description of the measurement configuration to measure the residual carrier suppression



Adjust Cp in Circuit 1 and Dynamic Residual Carrier Suppression to Suppression Maximum.

Figure 12

Description of the measurement configuration to measure the video amplitude response

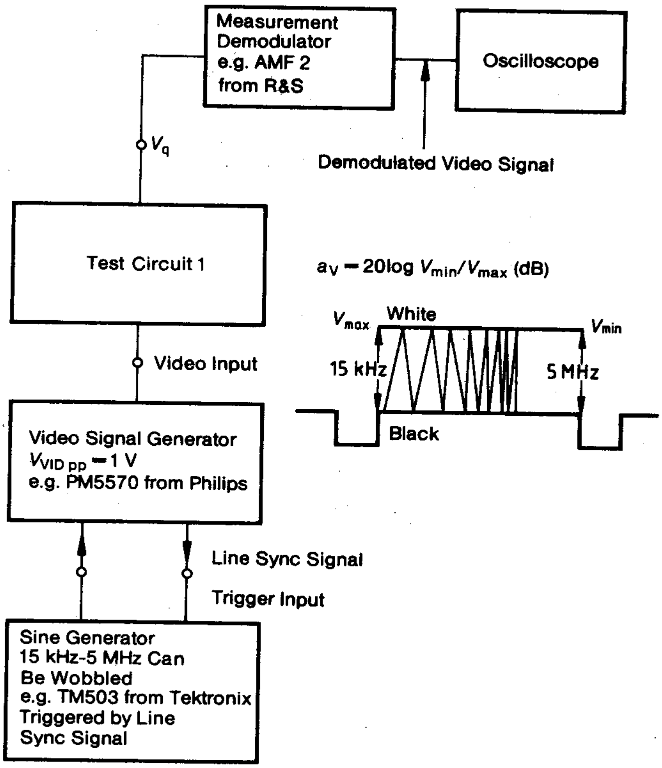
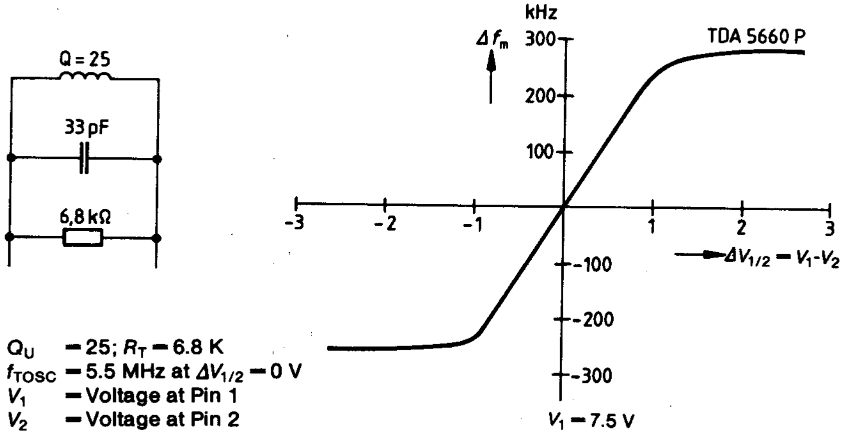


Figure 13

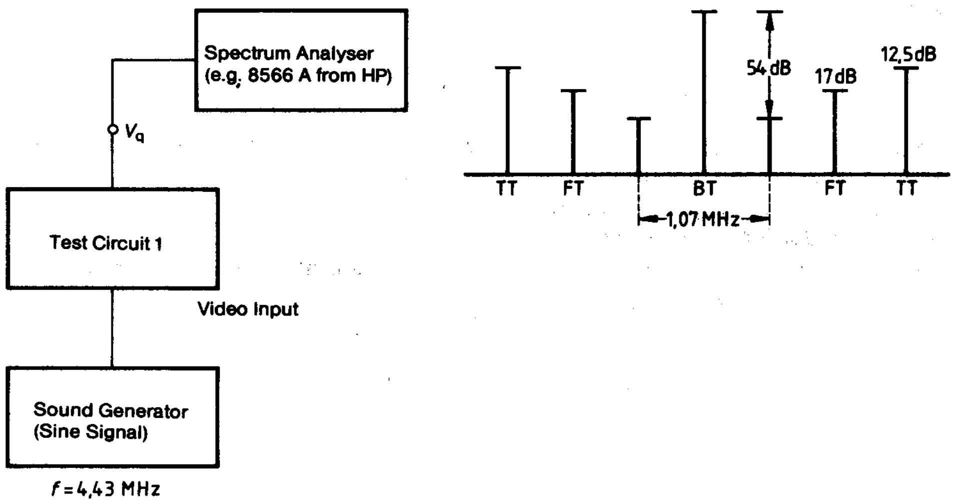
Static modulation characteristic of the FM sound modulator



Q_U = 25; R_T = 6.8 K
f_{TOSC} = 5.5 MHz at $\Delta V_{1/2}$ = 0 V
V_1 = Voltage at Pin 1
V_2 = Voltage at Pin 2

Figure 14

Description of the measurement configuration to measure the 1.07 MHz moires



$V_{VID\,pp}$ = 250 mV: Frequency carrier level lies below the activation point of the video amplitude control and has been set to provide a ratio of 17 dB with respect to the video carrier.

Figure 15

Modulation index during negative video modulation and/or the voltage at pin 12 versus current at pin 12

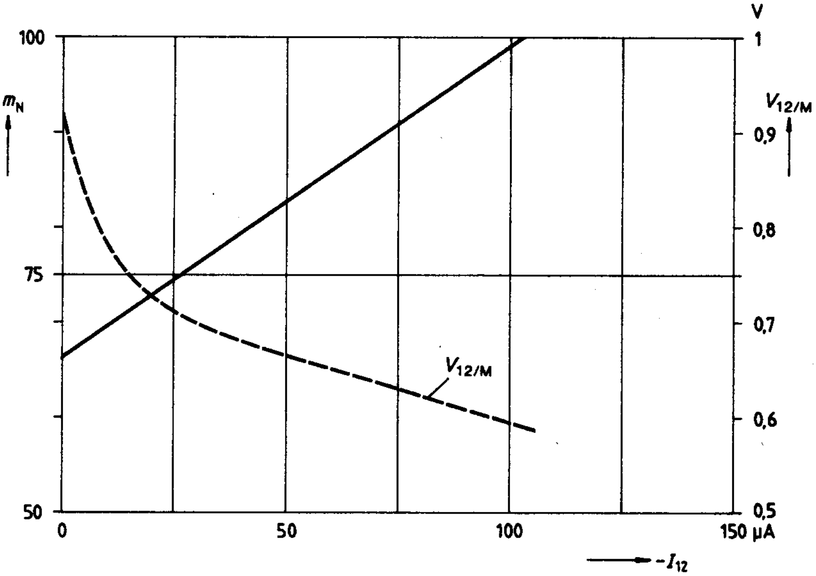


Figure 16 a

Modulation depth is calculated as $m_D = (2 \times m)/(1 + m)$ from the modulation index. Prerequisite is a sine-shaped modulation.

m_N = modulation index for negative modulation
m_P = modulation index for positive modulation

If a resistor is connected to ground at pin 12 to adjust modulation depth, the resistor is calculated as $R_{12/M} = (V_{12/M})/I_{12}$.

Modulation index during positive video modulation and/or the voltage at pin 12 versus current at pin 12

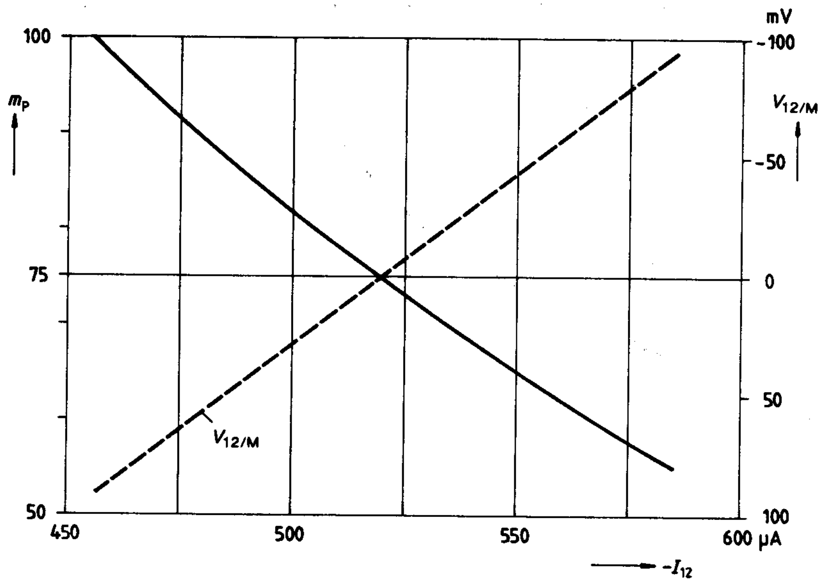


Figure 16

Modulation depth is calculated as $m_D = (2 \times m)/(1 + m)$ from the modulation index. Prerequisite is a sine-shaped modulation.

m_N = modulation index for negative modulation
m_P = modulation index for positive modulation

If a resistor is connected to ground at pin 12 to adjust modulation depth, the resistor is calculated as $R_{12/M} = (V_{12/M})/I_{12}$.

Picture to sound carrier ratio versus dc voltage offset at pin 16
unloaded Q factor of resonant circuit $Q_U = 25$, $R_T = 6.8$ k; $f = 5.5$ MHz.

The picture to sound carrier ratio of $a_{P/S} = 13$ dB was set via the loaded Q factor Q_L without external voltage at pin 16.

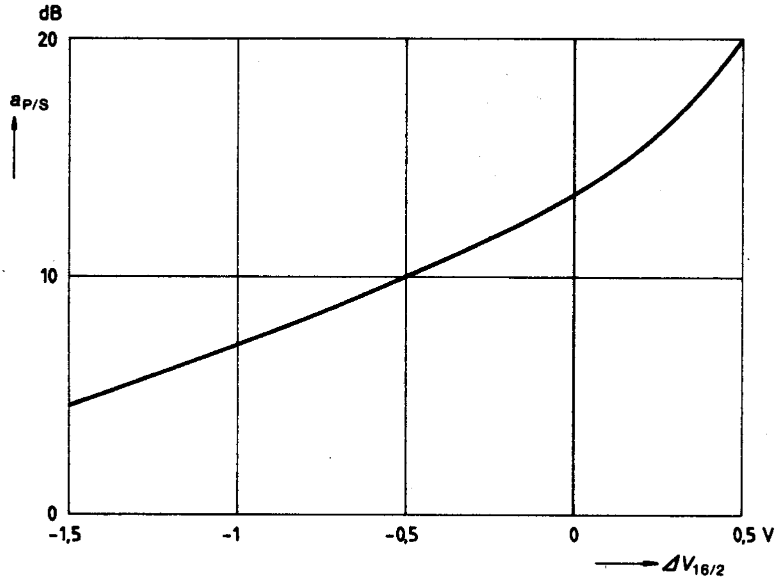


Figure 17

To adjust the picture to sound carrier ratio, a component was used with a resistance of typ. 11.5 kΩ at pins 17, 18.

The loaded Q factor of the resonant circuit was derived from the internal resistance $R_{17/18}$ connected in parallel with the external resistor R_s.

Measurement of the sound oscillator FM deviation without preemphasis and deemphasis; f_{AF} = 1 kHz; modulation deviation, sensitivity $(\Delta f_{AF})/(\Delta V_{AF})$ = 0.38 kHz/mV; V_{AF} = var; detector (P+P)/2; AF filter 30 Hz to 20 kHz, measurement in accordance with CCIR 468-2 DIN 45405; test circuit 1a.

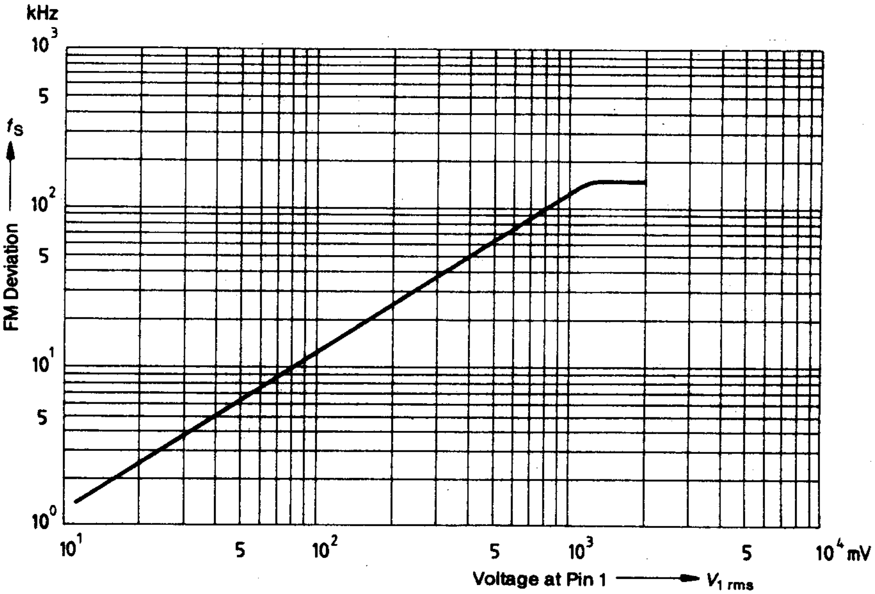


Figure 18

7

Measurement of the sound oscillator FM deviation without preemphasis and deemphasis; f_{AF} = 1 kHz; modulation deviation, sensitivity $(\Delta f_{AF})/(\Delta V_{AF})$ = 0.38 kHz/mV; V_{AF} = var; detector $(P+P)/2$; AF filter 30 Hz to 20 kHz, measurement in accordance with CCIR 468-2 DIN 45405; test circuit 1 a

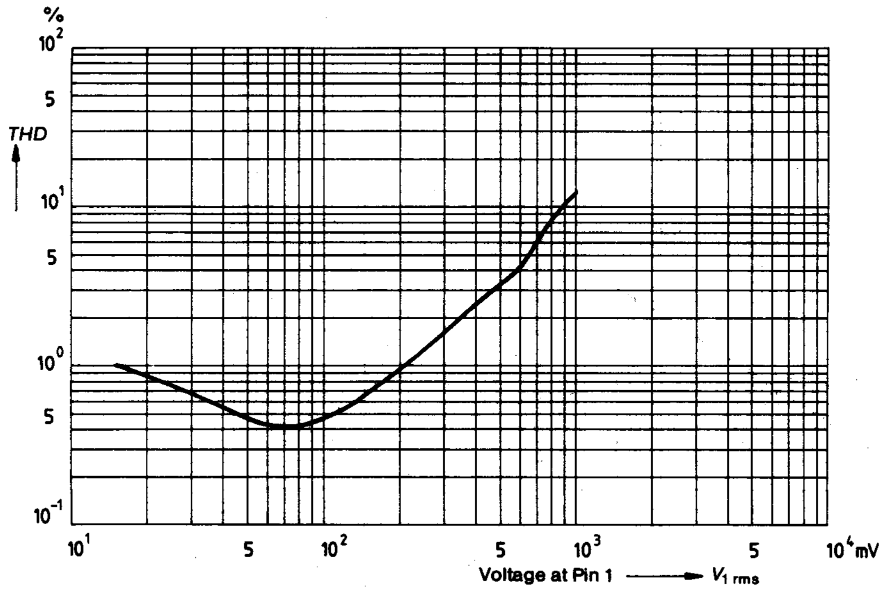


Figure 18 a

Sound oscillator harmonic distortion without preemphasis and deemphasis;
AF signal routed in at pin 1; AF amplitude = 150 mV_{rms}; AF filter 30 Hz to 20 kHz; detector $(P+P)/2$; measurement in accordance with CCIR 468-2 DIN 45405; test circuit 1a

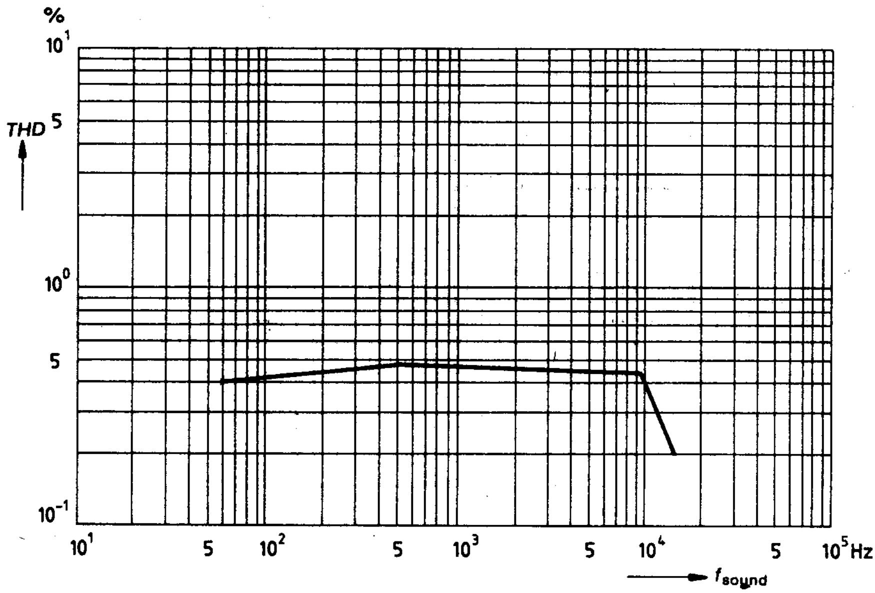


Figure 18 b

Sound oscillator frequency without preemphasis and deemphasis;
AF signal routed in at pin 1; AF amplitude = 150 mV_{rms}; AF filter 30 Hz to 20 kHz; detector $(P+P)/2$; measurement in accordance with CCIR 468-2 DIN 45405; test circuit 1a

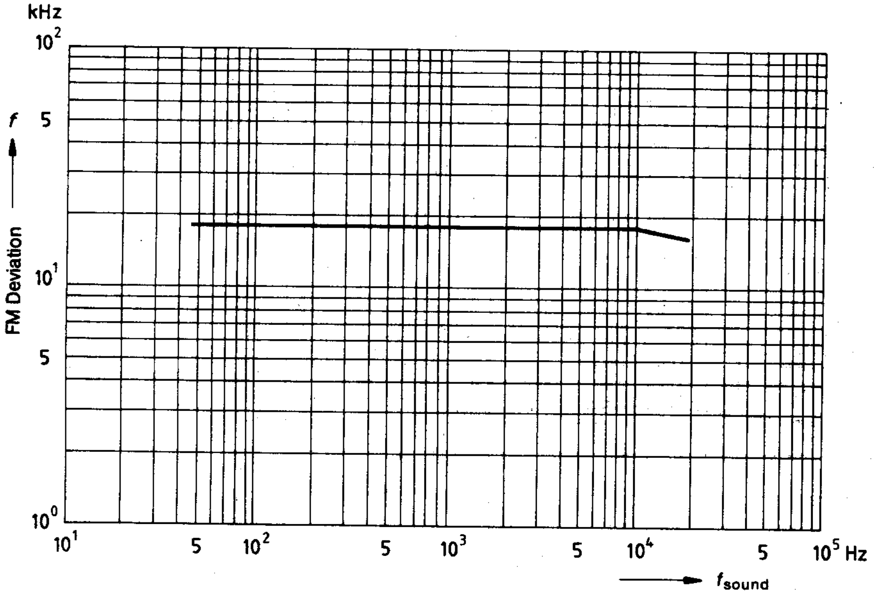


Figure 18 c

Sound oscillator frequency with pre-/deemphasis;
AF filter 30 Hz to 20 kHz; measurement in accordance with CCIR 468-2 DIN 45405; test circuit 1; $V_{AF} = 1\ V_{rms}$

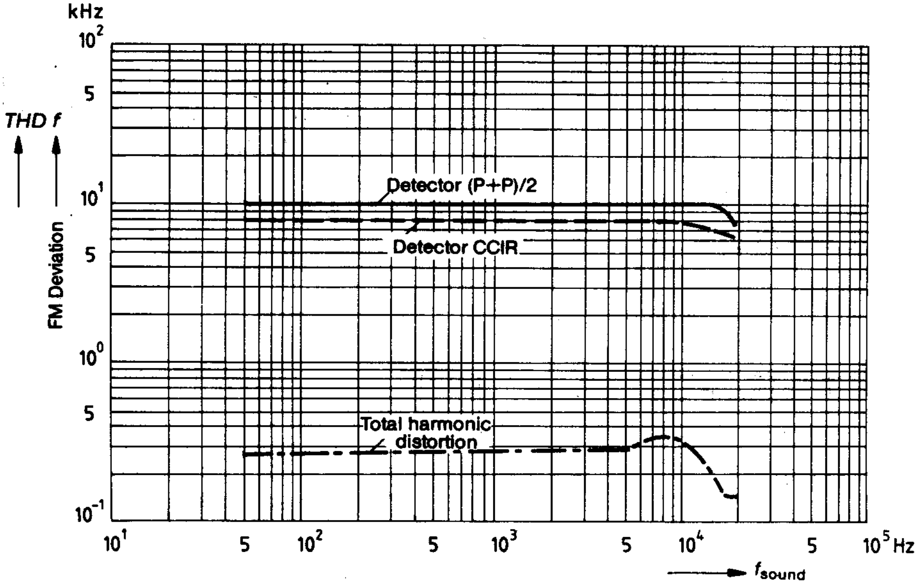


Figure 18 d

7

Description of the measurement configuration to measure the video signal control characteristics and the dynamic signal suppression in video frequencies

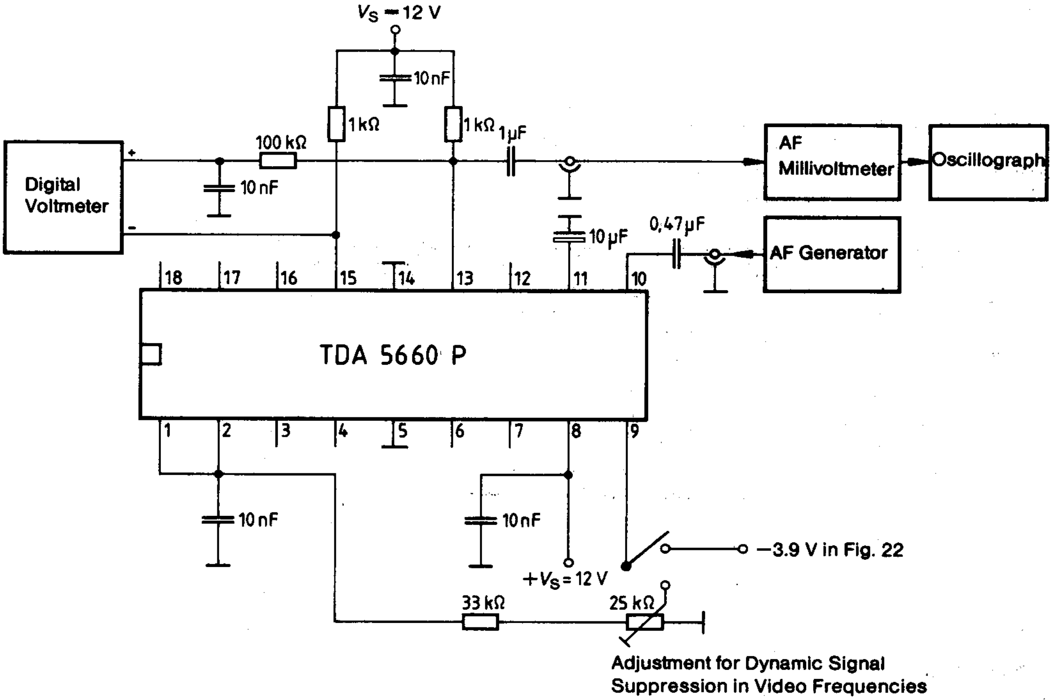
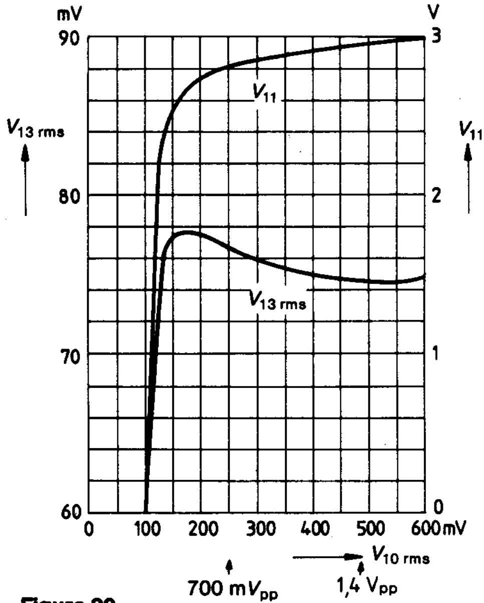


Figure 19

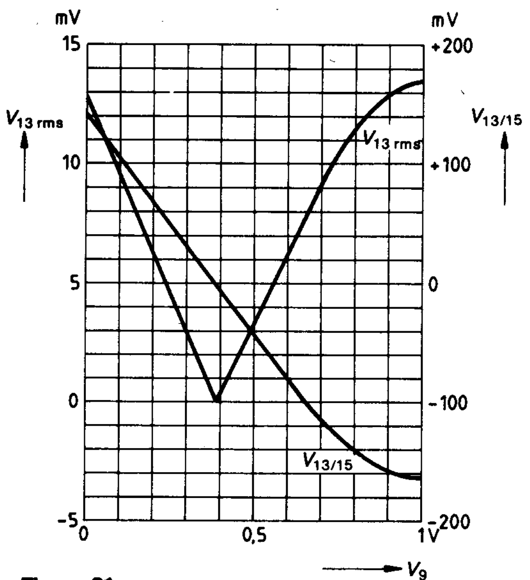
Characteristic of the video signal control circuit



a) $V_{13\,rms} = f\,(V_{10\,rms})$; $f_{mod} = 100$ kHz
b) $V_{11} = f\,(V_{10\,rms})$; $V_9 = 3.9$ V

Figure 20

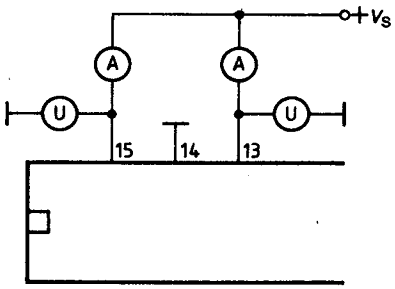
Static and dynamic mixer test with respect to balance characteristics based on a typical component



$V_{13/15} = f\,(V_9)$
$V_{13\,rms} = f\,(V_9)$
$f = 10$ kHz

Figure 21

Measurement of the static output impedance



$$Z_{15} = \frac{\Delta V_{15}}{\Delta I_{15}}$$

$$Z_{13} = \frac{\Delta V_{13}}{\Delta I_{13}}$$

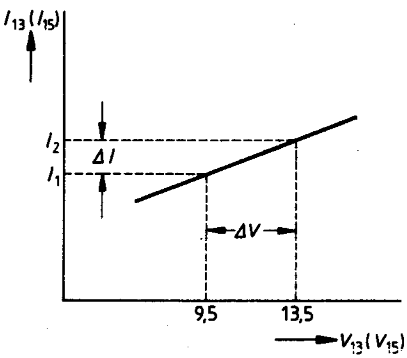
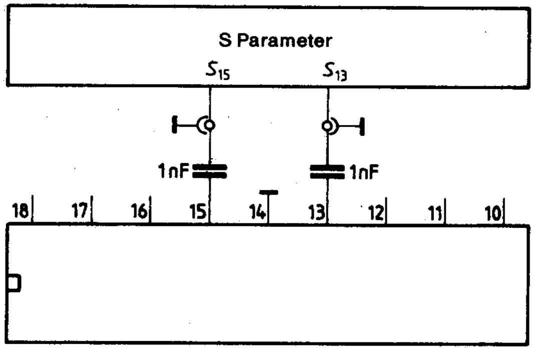


Figure 22

Output circuit S parameter



Typ. output capacity is approx. 1 pF

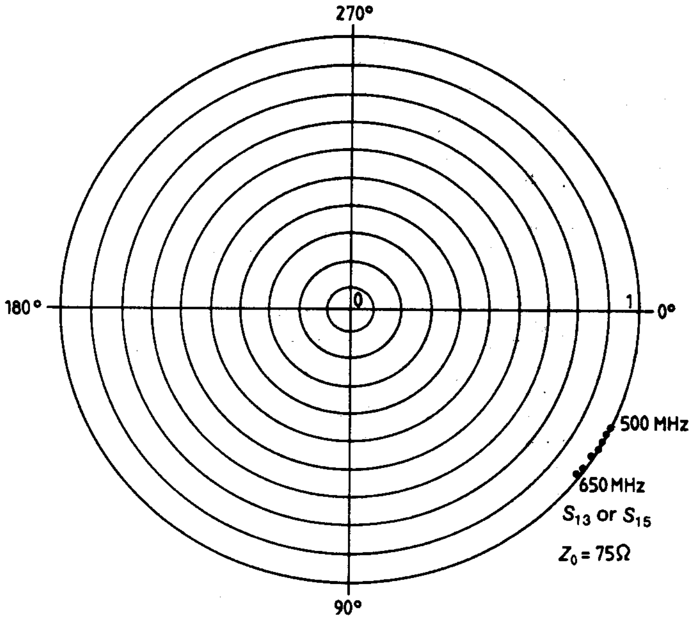
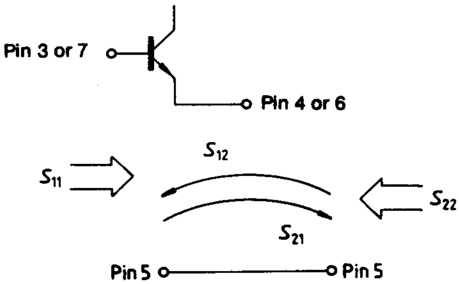
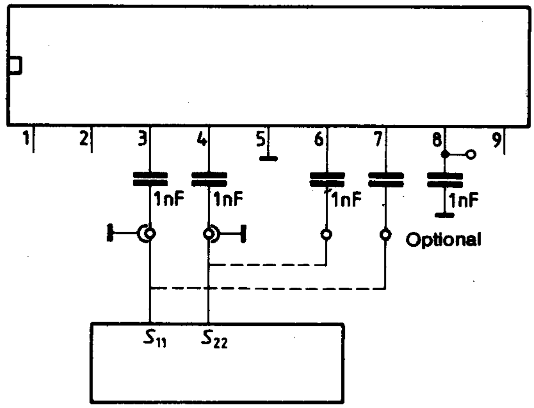


Figure 23

Oscillator section S parameter





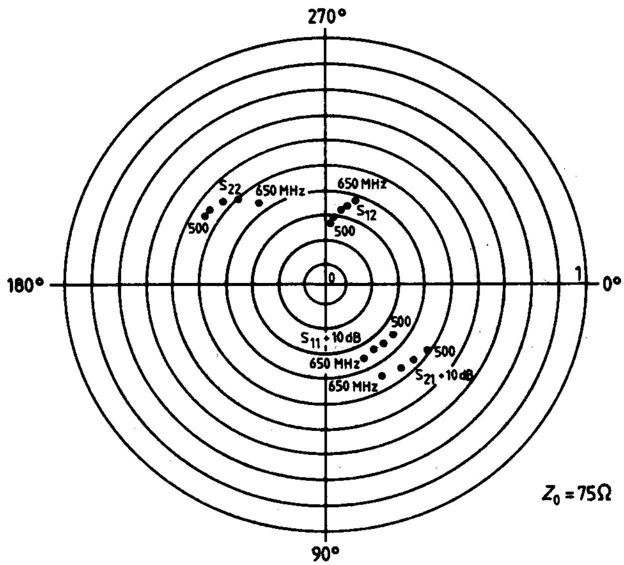
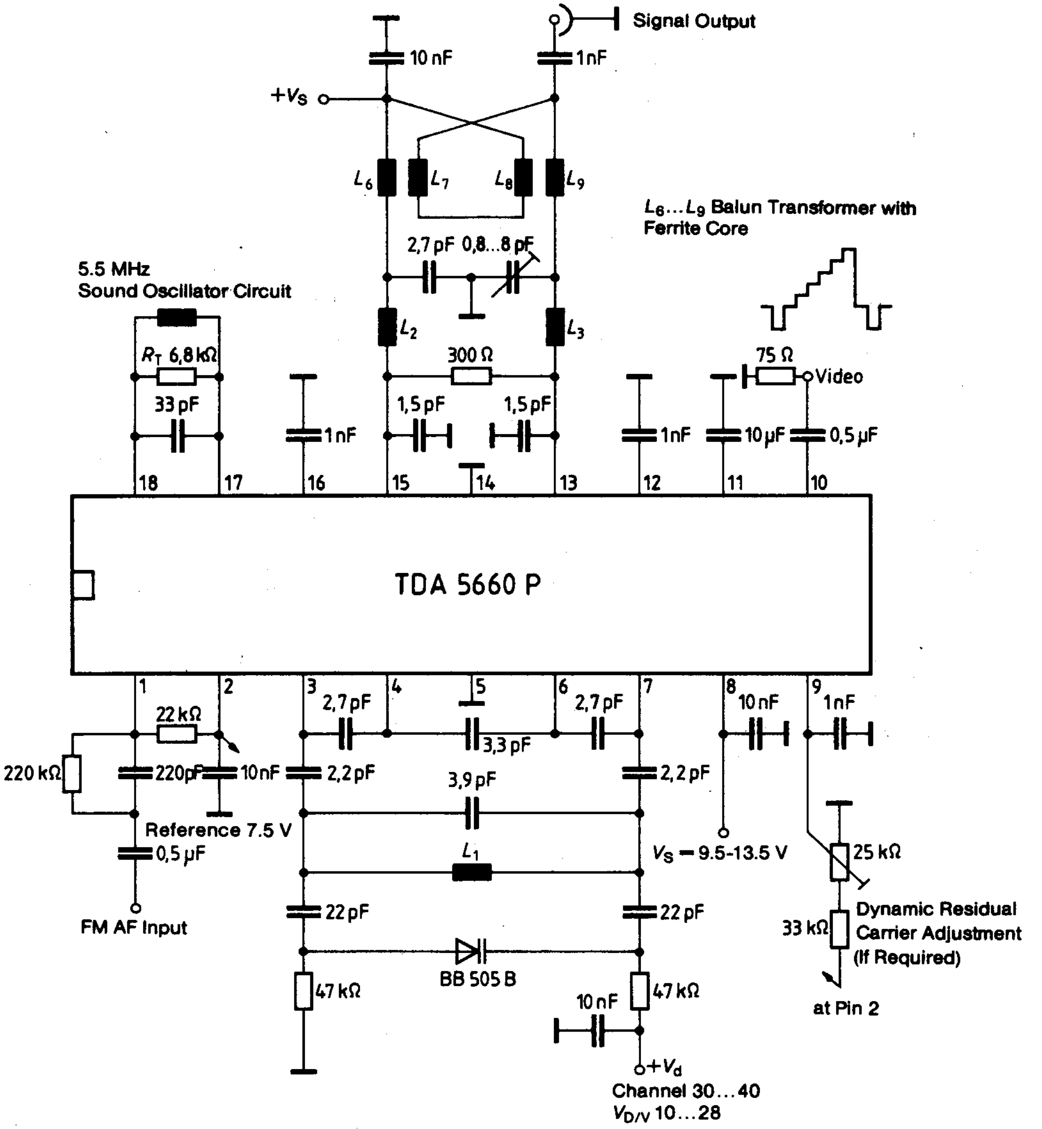


Figure 24

Application circuit 1



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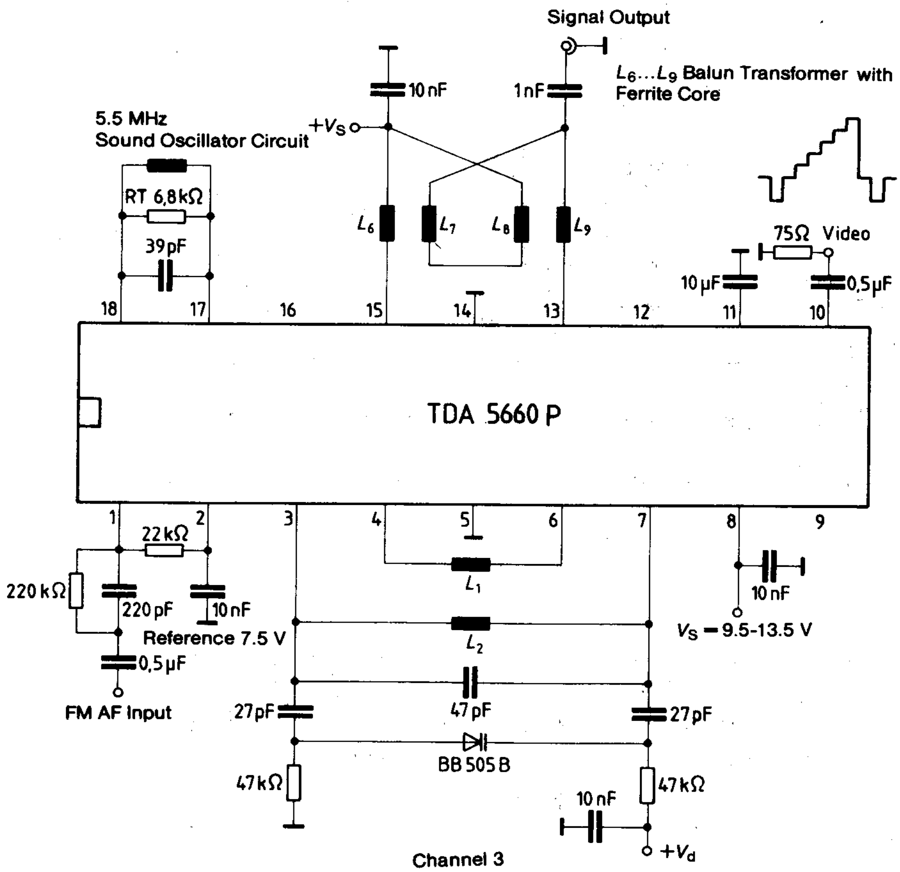
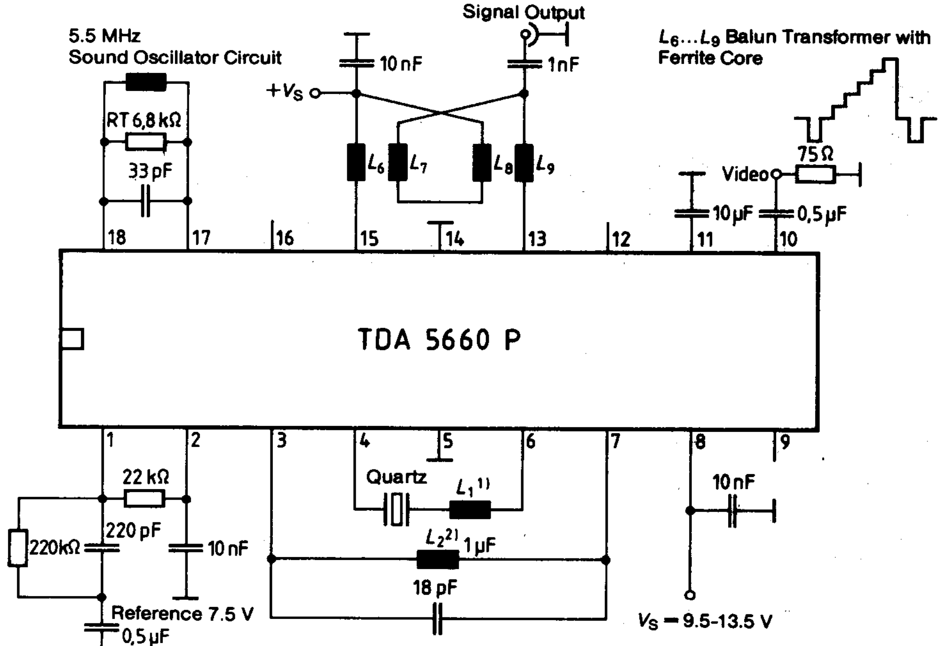
Application circuit 2



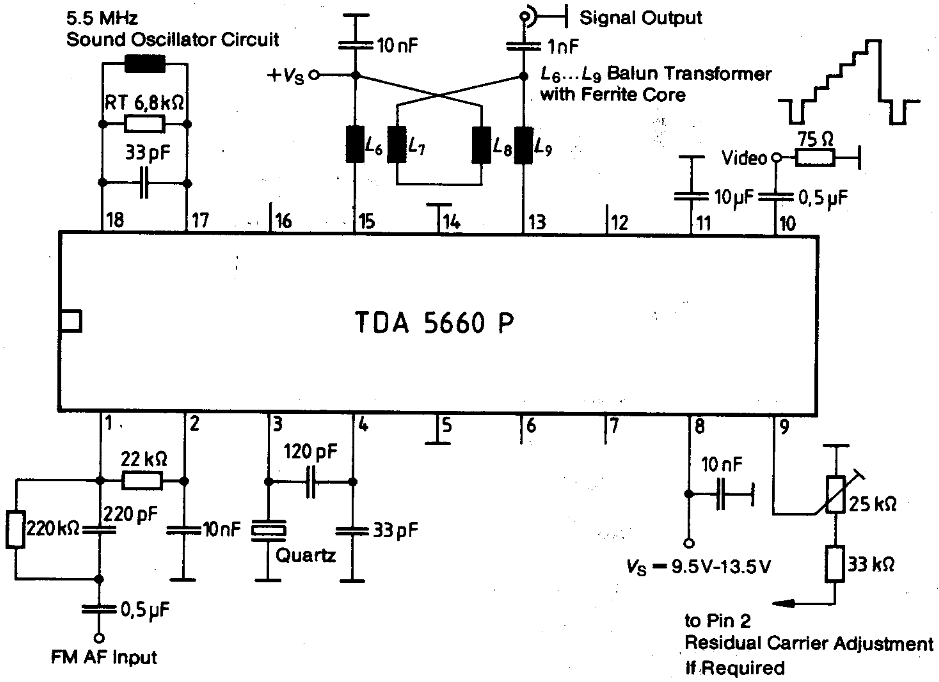
Application circuit 3



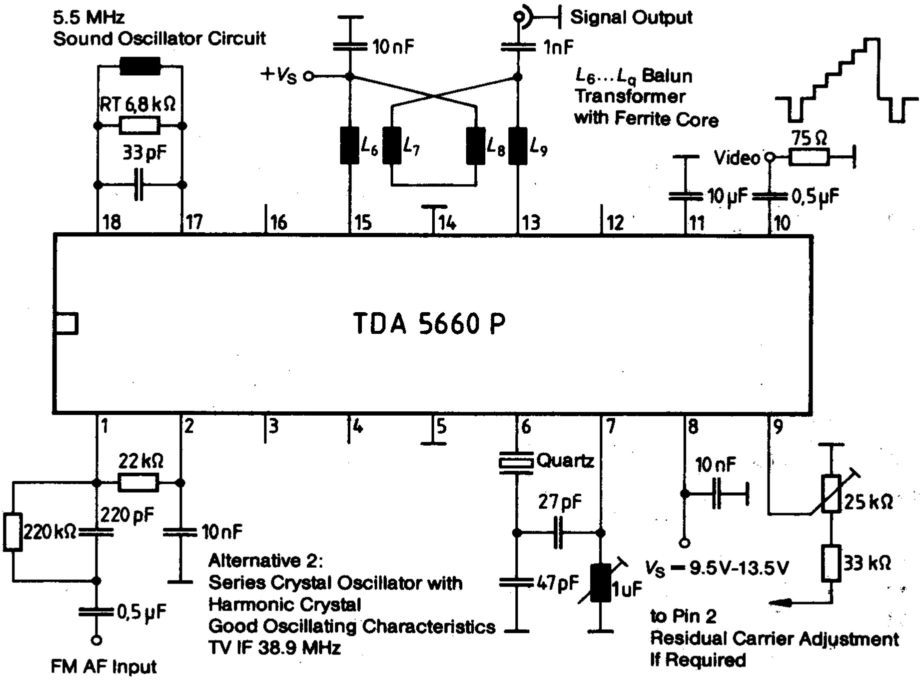
Symmetrical Oscillator Layout
Harmonic Crystal
Operated in Series Resonance
TV IF 38.9 MHz

IF Filter Neosid
1) 2 Turns
2) 12 Turns

Application circuit 4



Application circuit 5



Application circuit 6